Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-046-9582

Inclosure Materia	I.
Glass	
Overall Length:	
	hes and 0.357 inches
Terminal Length:	
Between 1.000 inc	hes and 1.625 inches
Overall Diameter:	
Between 0.215 inc	hes and 0.235 inches
Electrode Interna	Ily-electrically Connected To Case:
Cathode	
Mounting Method	
Terminal	
Features Provide	d:
Hermetically seale	d case
Semiconductor N	laterial:
Silicon	
Voltage Rating In	Volts Per Characteristic:
49.4 breakdown v	oltage, dc
Current Rating Pe	er Characteristic:
23.20 amperes rep	petitive peak forward current
Power Rating Per	Characteristic:
1.0 milliwatts smal	l-signal input power, common-collector major
Maximum Operat	ing Tempurature Per Measurement Point:
175.0 degrees cels	sius ambient air
Test Data Docum	ent:
81349-mil-s-19500	specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes of	commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and	performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type An	nd Quantity:
2 uninsulated wire	lead
Specification Dat	a:
81349-mil-s-19500	/500 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	